Piezoelectricity, that is, conversion of mechanical energy to electrical signals, is one of the most versatile phenomena to harvest energy to power small-scale electronic devices from the device environment. Zinc oxide (ZnO) has several key advantages in this area, being a biologically safe piezoelectric semiconductor occurring in a wide range of nanostructures such as nanowires, nanorods, and nanotubes.1–3 The existence of various 1D and 2D forms of ZnO opened opportunities for applications not only in energy harvesting but also in optoelectronics and photovoltaics.4,5 Nevertheless, the applications have been limited due to the poor control of self-assembled nanostructures that often lead to degradation of the device performance and make them inaccessible to many application areas.

Graphene is a two-dimensional (2D) system composed of carbon atoms arranged in a hexagonal, honeycomb lattice with a unique electronic structure; its excellent optical transparency, mechanical flexibility, thermal stability, and chemical inertness make it an ideal material for the realization of transparent electrodes, solar cells, photodetectors, nanogenerators, and light-emitting diodes.6–10 Owing to its linear energy-momentum dispersion relation, graphene has unique electronic structures of relativistic massless Dirac particles, high electron mobility approaching 200 000 cm² V⁻¹ s⁻¹, and excellent optical transmittance of ~97%, while maintaining high mechanical strength and thermal conductivity similar to carbon nanotubes.6,11

Recently, interest is growing in the integration of 1D (or 2D) semiconducting nanostructure/graphene systems10 that can offer a unique opportunity to study the physics at interfaces between semiconducting nanostructures and graphene. For example, semiconductor–graphene junctions with high-quality crystal structures can be ideal to lead to effective carrier transport at the interface between two nanostructures with significantly reduced carrier scattering or traps, as well as novel device structures that have not been accessible in isolated graphene and semiconducting nanostructures. In this respect, the platform of 3D nanoscale building blocks via the integration of semiconducting nanostructures with 2D graphene layers is very promising for the realization of graphene-based functional nanodevices.

Graphene layers can also be directly used to grow nanostructures with high crystallinity...
for use as device electrodes. ZnO nanostructures in 1D or 2D have been grown previously on highly oriented pyrolytic graphite using catalyst-assisted chemical vapor deposition (CVD) and on graphene sheets using metal organic CVD (MOCVD) and a solution approach. However, high-quality ZnO nanowires with high density, high aspect ratio, large-area uniformity, and perfect vertical alignment have not been obtained.

The purpose of this work is 2-fold: (i) to directly grow high-quality ZnO nanostructures on graphene layers in a controllable way without invoking damage on the graphene layers and (ii) to apply this structure to a graphene/ZnO-based direct current (DC) nanogenerator. The growth mode of ZnO on CVD-grown graphene layers was controlled precisely by varying gold (Au) layer thickness and growth time using thermal CVD. Our study shows that, with increasing Au thickness, the ZnO morphology gradually changed from a pure nanowire to a pure nanowall structure, through a hybridized state composed of interconnected nanostructures of nanowires and nanowalls, where the nanowires were perfectly aligned vertically on the (002) graphene surface at high temperature (900 °C). We found that the piezoelectric nanogenerator based on the nanowire–nanowall hybrid generated a DC type voltage. Such a DC type ZnO nanogenerator has been demonstrated before via lateral mechanical compression on bent nanowires, while the effect here is achieved through the specific electron dynamics in the nanowire–nanowall hybrid.

**RESULTS AND DISCUSSION**

The morphology of ZnO nanostructures is easily controlled by varying the Au layer thickness or the density of Au nanoparticles on the graphene. As the Au layer thickness was increased from 0.5 to 2 nm, the density of the Au nanoparticles also increased.

![Figure 1. Tilted-view FE-SEM images of ZnO (a) nanowires, (b) nanowire–nanowall hybrid, and (c) nanowall structures. Cross-sectional FE-SEM images of ZnO (d) nanowire, (e) nanowire–nanowall hybrid, and (f) nanowall structures on a graphene/Al2O3 substrate.](image)
The height of the nanowires increased from 1.5 to 120 min. On the graphene surface, Au interaction was stronger than Au nanoparticles on the graphene surface results in a more continuous network of nanowires grown directly from the nodes of the nanowalls. \( \text{ZnO (002)} \) and \( \text{ZnO (004)} \) planes of graphene and \( \text{ZnO (002)} \). This result indicates that graphene can be a novel platform to serve as a buffer layer for realization of \( \text{ZnO nanostructures} \) that are perfectly aligned perpendicular to a variety of substrates.

The above results provide detailed features of the growth process of \( \text{ZnO nanostructures} \), nanowalls, and hybrid nanowire—nanowall structures and elucidate the growth mechanism of graphene-based \( \text{ZnO nanostructures} \). The growth mechanism of the nanowires is shown in Figure 4a. First, \( \text{Zn vapor} \) is generated by the thermal carbon reduction of \( \text{ZnO in the source region at high temperature. The metallic Zn vapor is then transferred to the Au-decorated graphene. A portion of the Zn vapor is adsorbed directly onto the Au nanoparticles on the} \)
graphene surface, and the rest of the Zn vapor produces droplets on the graphene. Zn droplets that migrate from the graphene surface to the nanosized Au droplets act as energetically favorable sites for ZnO nanostructure growth. This is due to the higher sticking coefficient of ZnO with liquid Au droplets, and the lower sticking coefficient with the solid graphene surface. As a result, Zn droplets preferably migrate from the graphene surface to the Au droplets (step I).

Second, because of the large quantity of Zn that has migrated from the graphene surface and the continuous supply of Zn prior to Zn and Au becoming soluble, further deposition produces the outer layers that encapsulate the Zn-adsorbed Au nanoparticles. The perfect epitaxial relation of Au (111) with graphene (002) forces the Au nanoparticles to bind with the graphene layer (step II). From the measurement of the in-plane diffusion of Au on graphene at 600 °C, Gan et al. obtained a diffusion coefficient, $D$, between $6 \times 10^{-22}$ and $2 \times 10^{-21} \text{ m}^2 \text{ s}^{-1}$. The diffusion coefficient is related to the activation energy, $E_a$, required for atoms to jump by

$$D \propto \exp\left(-\frac{E_a}{K_B T}\right)$$

(1)
where $T$ is temperature and $k_B$ Boltzmann’s constant. In our experiments, the growth temperature of 900 °C is high enough for Au atoms to heavily diffuse through the graphene surface, resulting in the formation of strong covalent bonds between Au and carbon atoms within the graphene network.

In the next step, the O component supplied from the residual air dissolves into the Zn liquid droplets, and, as a result, growth of the ZnO nanostructures from energetically favorable Au sites occurs (step III). The continuous supply of Zn and O vapors saturates the outer layers, followed by precipitation of the ZnO nanowires. Step IV shows how the ZnO nanowires grow from the outer layers through the self-catalytic vapor–liquid–solid (VLS) process. The outer diameter of the Zn droplets encapsulating the Au nanoparticles restricts the diameter of the ZnO nanowires within the nanometer range. The maximum number and diameter of ZnO nanowires depends on the density and diameter of the Au droplets. Zn droplets encapsulating the Au act as a self-catalyst in VLS growth, and the length of the ZnO nanowires increases with growth time.

ZnO nanowires grow if the density of Au nanoparticles is not too high and Au nanoparticles are well separated from each other. If the distance between the Au droplets that act as nucleation sites on the graphene is very small (less than the diameters of the nanowires), then the Zn droplets that encapsulate the Au and act as a self-catalyst will quickly merge together and form a continuous network of Zn droplets. As a result, nanowalls grow through the same self-catalytic VLS process depicted in the schematic diagram shown in Figure 4b.

Previous research has shown that self-generated clusters from the source can exhibit diffusion along or within the nanowires during growth at high temperature. In the nanowire–nanowall hybrid structure, the nanowalls grow first as a result of dense Au nanoparticles located on the graphene surface, and then nanowires grow from the nodes of the nanowall networks. On the inclined nanowall surface toward the nodes, Zn droplets drift and aggregate at the nodes. Because of the high surface energy at the node, Zn droplets accumulate at the nodes for overall energy compensation. Therefore, ZnO nanowires begin to form from the nodes through the self-catalytic VLS process at the critical point. Nanowires also grow from the less dense Au nanoparticles on the graphene surface in the hybrid structure through the same self-catalytic process, which is described in Figure 4a. Figure 4c shows a schematic diagram of the time-dependent ZnO nanowire–nanowall hybrid structure growth mechanism. This study suggests that Au plays an important role in the formation of these useful and novel ZnO nanowire, nanowall, and nanowire–nanowall hybrid structures on graphene.

Further, we demonstrated DC type piezoelectric nanogenerators as a potential application of this novel nanowire–nanowall hybrid structure. The generated output was measured from the nanogenerator fabricated with Au-coated polyethersulfone (PES) as a top electrode and the remaining graphene layer as a bottom electrode. A compressive force (0.5 kgf) was applied to the top of the nanogenerator in the direction perpendicular to the electrode. Figure 5 panels a and b show the current density and voltage generated from the ZnO nanowire–nanowall hybrid nanogenerator, respectively. The output current density was approximately 500 nA cm$^{-2}$, and the output voltage was about 20 mV. Despite the 400 Ω sheet resistance of the graphene, which is much larger than the 60 Ω of the commercially available indium tin oxide, a DC output current was successfully and clearly detected. The output current peaks were sharp and narrow. We believe that the output power can be further improved by using graphene with a lower sheet resistance and a ZnO hybrid structure with a larger height.

To verify that the measured signal was from nanogenerators rather than the measurement system, we performed "switching-polarity" tests, as shown in Figure 5. When the current and voltage meters were initially connected to the nanogenerator, positive pulses
were recorded during the pushing. When the current and voltage meters were connected in using reverse polarity, the pulses were also reversed. The output current density and voltage for both connecting conditions were about the same. The measured voltage of 20 mV from the nanogenerator is much lower than the calculated piezoelectric potential of \( \sim 0.63 \) eV. Further, the calculated potential is higher than the Schottky barrier height of the Au–ZnO interface (approximately 0.40 eV\(^2\)). The piezoelectric potential generated in the ZnO hybrid structure is sufficient to drive the piezoelectric induced electrons from the top Au electrode to the bottom graphene electrode. This piezoelectric potential was calculated using the relation \( V_{\text{max}} = F g_{33} L / A \), where \( F \) is the force applied on the top electrode (0.5 kgf), \( g_{33} \) is the piezoelectric voltage coefficient of the ZnO nanowires (0.135 Vm/N\(^2\)) neglecting the change in the piezoelectric voltage coefficient by nanostructuring of ZnO), \( L \) is the length of the nanowires in the hybrid structure used to fabricate the nanogenerator (3 \( \mu \)m), and \( A \) is contact area of the nanowires (3.14 mm\(^2\)).

The following explanation may account for this discrepancy. First of all, the contact resistance may have been very large as a result of the small contact area between the ZnO nanowires and electrode. Therefore, the voltage created by the piezoelectric effect is largely consumed at the contact and only a small portion is received as the output.\(^2\) Second, the free carriers in the nanowalls screened the piezoelectric potential generated in the nanowires, which could be another reason for the low measured voltage and current. Figure 6 shows a schematic illustration of an integrated nanogenerator with a Au top electrode and a piezoelectric ZnO nanowire–nanowall hybrid structure grown on a graphene/Al\(_2\)O\(_3\) substrate along with its working mechanism.

The work function of the graphene electrode was about 4.53 eV and the electron affinity of ZnO is 4.35 eV.\(^2\) Hence, a weak Schottky contact is formed at the interface between the graphene and ZnO nanostructures. As we apply the force in the vertical direction on the top electrode of the nanogenerator, the top surface of the nanowires reveals a negative potential \( (V_{1}^-) \) and the bottom surface shows positive a potential \( (V_{1}^+) \). Subsequently, the force-induced piezoelectric potential at the top surface drives the flow of the electrons from the top electrode to the bottom electrode, which consequently produces the measured current pulse during pushing.

In the nanowire–nanowall hybrid structure, some of the positive potential is screened by the free electrons present near the nanowalls. Thus, the magnitude of \( V_{2}^+ \) will be reduced as the electrons move from the top electrode and penetrate into the ZnO area, contacting the graphene electrode by passing through the weak Schottky barrier. As a result, this weak positive potential is not sufficient to drive back the electrons accumulated near the bottom electrode toward the top electrode. Therefore, no current pulses are measured in releasing the force, resulting in DC-type power generation from the nanowire–nanowall hybrid structure-based nanogenerator.

**CONCLUSIONS**

\( c \)-Axis-oriented novel ZnO nanowires, nanowire–nanowall hybrids, and nanowall structures with the graphene (002) plane were grown for use in
functional nanoscale electronic and optoelectronic devices. It was found that Au plays an important role in the formation of the ZnO nanowire, nanowall, and nanowire–nanowall hybrid structures on graphene. A new growth mechanism of the ZnO nanowire, nanowall, and nanowire–nanowall hybrid structures on graphene was proposed in detail. Furthermore, we demonstrate that a DC output power can be generated by the piezoelectric ZnO/graphene nanogenerator due to the electron dynamics specific to the nanowire–nanowall hybrid structure.

METHODS
To grow the graphene sheets, a 300 nm-thick nickel layer was first deposited on a 4” SiO2/Si wafer using an electron-beam evaporator. The Ni-coated substrate was placed in a rapid thermal CVD chamber and the temperature was increased from room temperature to 1000 °C in 5 min. The initial reduction of the Ni-coated substrate was carried out under a hydrogen gas flow of 45 standard cubic centimeters per minute (scm) for 20 min at 1000 °C. The synthesis of the graphene sheets was achieved with a C2H2/H2 flow ratio of 2/45 sccm with a growth time of 2 min. After the growth was completed, the gas supply was terminated and the chamber was cooled to 500 °C at a cooling rate of 160 °C min⁻¹. Finally, the graphene sheet was transferred to c-Al2O3. The details have been described elsewhere.

ZnO nanowires, nanowires–nanowalls hybrid, and nanowall structures were grown on a horizontal tube furnace by thermal CVD. Au layers with thicknesses of 0.5, 1.0, and 2.0 nm were coated onto graphene/c-plane Al2O3 substrates as nucleation seeds to grow highly aligned ZnO nanowires and nanowall arrays by thermal evaporation. ZnO nanowires and nanowalls were obtained from a carbothermal reaction by evaporating a mixture of ZnO (99.999% purity) and graphite (99.999% purity) powder (1:1) in an argon (Ar) atmosphere. A quartz boat containing both the substrate and powder mixture was placed in the central hot zone inside the tube furnace. Once Ar gas flow was stabilized at 1000 sccm, the tube was heated to 900 °C for 60 min.

Morphologies of the ZnO nanosstructures were examined by FE-SEM. The structural properties of the samples were determined by XRD measurements and HR-TEM. ZnO/graphene heterojunctions were further investigated using μ-EDS. The Au top electrode of the piezoelectric generator was deposited on a plastic substrate by a thermal evaporator and was then pressed onto the ZnO structure. A Keithley 6485 picoammeter and 2182A voltmeter were used to measure the low-noise output current and voltage generated from the piezoelectric nanogenerators.

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Supporting Information Available: The cross-sectional HR-TEM image and the μ-EDS spectrum of the nanowire–nanowall hybrid structure on a graphene/Al2O3 substrate for Au nanoparticles mapping. This material is available free of charge via the Internet at http://pubs.acs.org.

REFERENCES AND NOTES


